NSN 5961-01-262-4259

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-262-4259 **Inclosure Material:** Metal **Overall Length:** 9.700 inches **Overall Diameter:** 1.690 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak reverse voltage and 400.0 working peak reverse voltage **Current Rating Per Characteristic:** 500.00 amperes collector current, dc **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0